



DMN12M7UCA10

N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{SSS}	R _{SS(ON)} Typ	Is мах Та = +25°С
12V	2.3 mΩ @ V _{GS} = 3.8V	20.2A

Description

This new generation MOSFET is designed to minimize the on-state resistance (Rss_(ON)) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Battery Management
- Load Switch
- Battery Protection

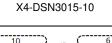
Features

- CSP with Footprint 2.98mm × 1.49mm
- Height = 0.11mm for Low Profile
- ESD Protection of Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

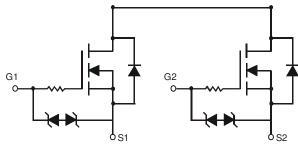
- Case: X4-DSN3015-10
- Terminal Connections: See Diagram Below
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu or NiAu. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.0012 grams (Approximate)







Source 1: 1,2,4,5 Top View Gate 1: 3 Source 2: 6, 7, 9, 10 Gate 2: 8



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN12M7UCA10-7	X4-DSN3015-10	5000/Tape & Reel

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

	MF	
•	ΥM	

 $\begin{array}{l} MF = Product Type Marking Code \\ YM = Date Code Marking \\ Y \ or \ \overline{Y} = Year \ (ex: G = 2019) \\ M \ or \ \overline{M} = Month \ (ex: 9 = September) \end{array}$

Date Code Key

Notes:

Year	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	F	G	Н		J	K	L	М	N	0	Р	R
	1					1	1					
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit			
Source-Source Voltage	Vsss	12	V			
Gate-Source Voltage			VGSS	±8	V	
	Steady	T _A = +25°C		20.2	А	
Continuous Source Current (Note 5) $V_{GS} = 4.5V$	State	$T_A = +70^{\circ}C$	Is	16.1		
		13.6	A			
Continuous Source Current (Note 5) V _{GS} = 2.5V	Is	10.8				
Pulsed Source Current (Note 6)	I _{SM}	80	А			

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 7)	PD	0.74	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 7)	R _{0JA}	171.9	°C/W
Power Dissipation (Note 5)	PD	1.73	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	Reja	74.4	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 8)								
Source-Source Breakdown Voltage	BV _{SSS}	12	—	—	V	$V_{GS} = 0V, I_S = 1mA$		
Zero Gate Voltage Drain Current TJ = +25°C	lsss	_	—	1	μA	$V_{SS} = 9.6V, V_{GS} = 0V$		
Gate-Source Leakage	la sa	—	—	±10	μA	$V_{GS} = \pm 8V, V_{SS} = 0V$		
Gale-Source Leakage	IGSS	_	—	±1	μA	$V_{GS} = \pm 5V, V_{SS} = 0V$		
ON CHARACTERISTICS (Note 8)								
Gate Threshold Voltage	V _{GS(TH)}	0.5	0.8	1.4	V	Vss = 10V, ls = 1.11mA		
		1.55	2.19	2.75		V _{GS} = 4.5V, I _S = 6A		
Static Source-Source On-Besistance	Descent	1.6	2.30	2.85		V _{GS} = 3.8V, I _S = 6A		
Static Source-Source On-Resistance	R _{SS(ON)}	1.65	2.51	3.95	mΩ	V _{GS} = 3.1V, I _S = 6A		
		1.9	2.93	6.1		V _{GS} = 2.5V, I _S = 6A		
Diode Forward Voltage	V _{SS}	_	0.8	1.2	V	$V_{GS} = 0V, I_S = 6A$		
DYNAMIC CHARACTERISTICS (Note 9)								
Input Capacitance	Ciss	_	3039	_				
Output Capacitance	Coss	_	530	—	pF	Vss = 10V, Vgs = 0V, f = 1MHz		
Reverse Transfer Capacitance	Crss	—	141	—				
Total Gate Charge	Qg	_	35.7	_				
Gate-Source Charge	Qgs	—	6.7	—	nC	$V_{SS} = 6V, V_{GS} = 4V,$		
Gate-Drain Charge	Q _{gd}	_	9.2	_	no	$I_{\rm S} = 6A$		
Gate Charge at V⊤н	Qg(th)	-	3.4	_				
Turn-On Delay Time	tD(ON)		880					
Turn-On Rise Time	t _R		1468			$V_{SS} = 6V, V_{GS} = 4V,$		
Turn-Off Delay Time	td(OFF)		2914		ns	Is = 6A		
Turn-Off Fall Time	t⊨		2830					

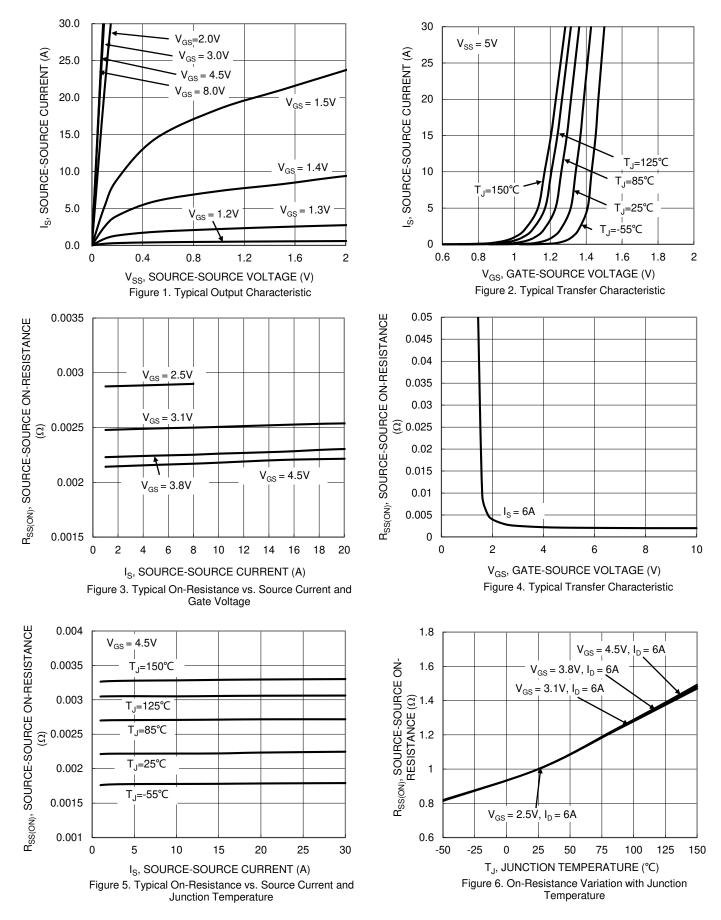
 Device mounted on FR-4 material with 1inch² (6.45cm²), 2oz. (0.071mm thick) Cu.
Repetitive rating, pulse width limited by junction temperature.
Device mounted on FR-4 PCB with minimum recommended pad layout, single sided. Notes:

8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to production testing.

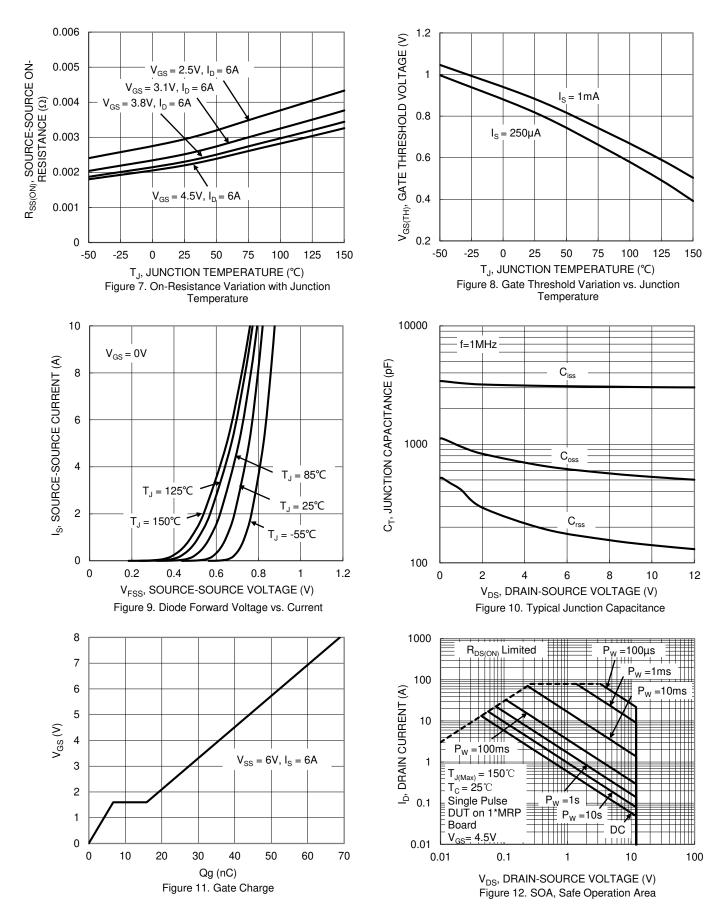


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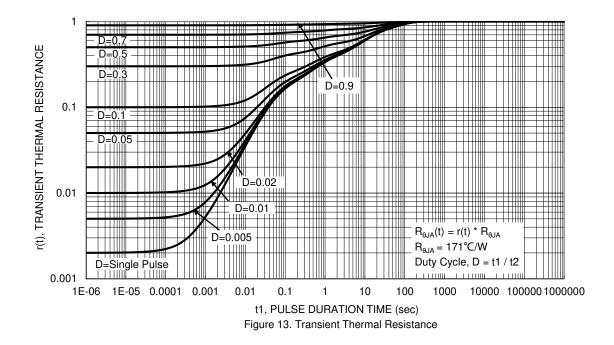
DMN12M7UCA10 Document number: DS40841 Rev. 3 - 2









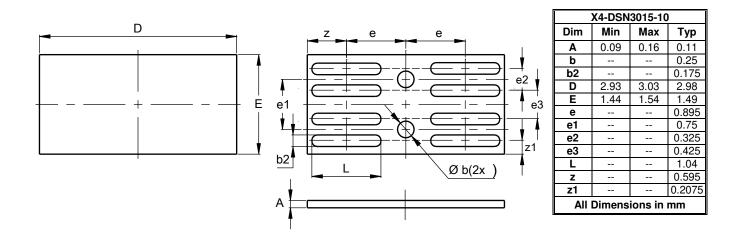




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

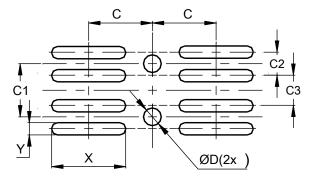
X4-DSN3015-10



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X4-DSN3015-10



Dimensions	Value
Dimensions	(in mm)
С	0.895
C1	0.750
C2	0.325
C3	0.425
D	0.25
Х	1.04
Y	0.175



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